



# Tyrystor C106M (4A/600V) TO-126 CDIL RoHS



## Dane techniczne:

Nazwa: C106M

Typ: Tyrystor

Napięcie wsteczne: 600V

Prąd przewodzenia: 4A

Prąd bramki: 0.2mA

Obudowa: TO-126

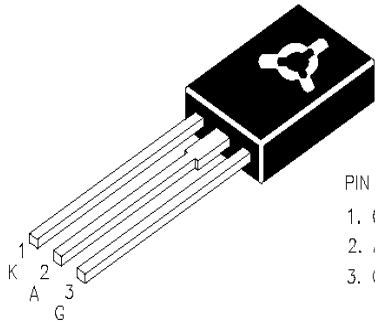
Producent: CDIL

**SCR**

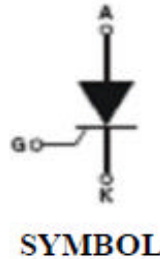
**C106M, C106D**

**TO-126**

**Plastic Package**



PIN CONFIGURATION:-  
 1. CATHODE  
 2. ANODE  
 3. GATE



**Features :**

- . High Blocking Voltage
- . Low On-State Voltage and high  $I_{TSM}$
- . RoHS Compliant

**Description :**

Suitable to fit all Models of Control like Phase control, Heating Control, Voltage Regulation Circuits etc.

**ABSOLUTE MAXIMUM RATINGS ( $T_J=25^\circ\text{C}$ , unless otherwise specified)**

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNIT
Repetitive Peak Off-State Voltage	$V_{DRM}$	C106M		600	V
		C106D		400	
Repetitive Peak Reverse Voltage	$V_{RRM}$	C106M		600	V
		C106D		400	
Average On-State Current	$I_{T(AV)}$	Half Sine wave, $T_{amb} \leq 109^\circ\text{C}$		2.5	A
On-State RMS Current	$I_{T(RMS)}$	All Conduction Angles		4	A
Non-Repetitive Surge Peak On-state Current	$I_{TSM}$	Full Sine Wave, $T_J=25^\circ\text{C}$ , $t=10\text{ms}$		40	A
		$I^2t$	$t=10\text{ms}$	6	
Repetitive Rate of Rise of On-State Current After Triggering	$di/dt$	$I_{TM}=20\text{A}$ , $I_G=0.2\text{A}$ , $dI_G/dt=0.2\text{A}/\mu\text{s}$		50	$\text{A}/\mu\text{s}$
Peak Gate Current	$I_{GM}$			0.5	A
Peak Gate Power	$P_{GM}$			1	W
Average Gate Power	$P_{G(AV)}$	over any 20ms period		0.2	W
Storage Temperature Range	$T_{STG}$		-40	150	$^\circ\text{C}$
Operating Junction Temperature	$T_J$			125	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Repetitive Forward Blocking Current	I <sub>DRM</sub>	V <sub>DM</sub> =V <sub>DRM(MAX)</sub> , T <sub>J</sub> =125°C		0.1	0.5	mA
Peak Repetitive Reverse Blocking Current	I <sub>RRM</sub>	V <sub>RM</sub> =V <sub>RRM(MAX)</sub> , T <sub>J</sub> =125°C		0.1	0.5	mA
Peak On-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> =4A		1.3	2.2	V
Gate Trigger Current	I <sub>GT</sub>	V <sub>DM</sub> =12V, I <sub>T</sub> =0.1A		50	200	μA
Gate Trigger Voltage	V <sub>GT</sub>	V <sub>DM</sub> =12V, I <sub>T</sub> =0.1A		0.4	1.5	V
Holding Current	I <sub>H</sub>	V <sub>DM</sub> =12V, I <sub>GT</sub> =0.1A		0.3	6	mA
Latching Current	I <sub>L</sub>	V <sub>DM</sub> =12V, I <sub>GT</sub> =0.1A		0.4	10	mA
Rise of Off-State Voltage	dV/dt	V <sub>DM</sub> =67%V <sub>DRM(MAX)</sub> , T <sub>J</sub> =125°C	50	100		V/μs
Gate Controlled Turn-On Time	t <sub>gt</sub>	I <sub>TM</sub> =40A, V <sub>DM</sub> =V <sub>DRM(MAX)</sub> , I <sub>G</sub> =0.1A, dI <sub>G</sub> /dt=5A/μs		2		μs

**THERMAL RESISTANCE**

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Junction to Case (AC)	R <sub>th(J-C)</sub>			3.0	K/W
Junction to Ambient	R <sub>th(J-A)</sub>		75		K/W

### TYPICAL CHARACTERISTICS CURVES

Fig. 1: Maximum average power dissipation versus average on-state current.

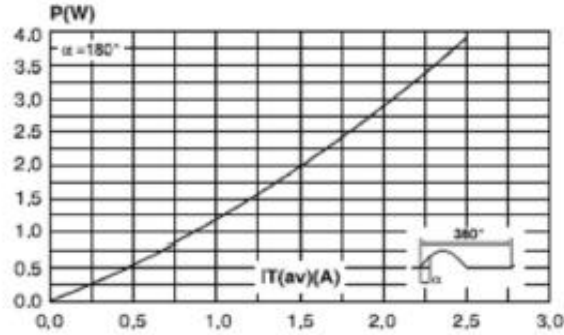


Fig.2 On-state characteristics (maximum values).

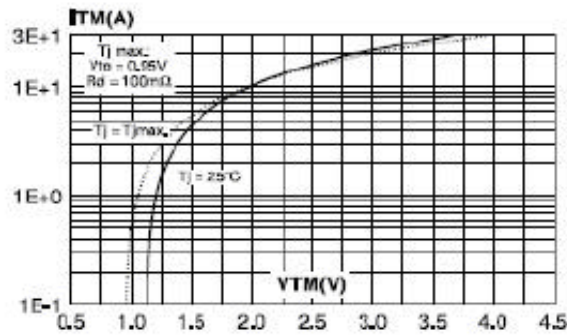
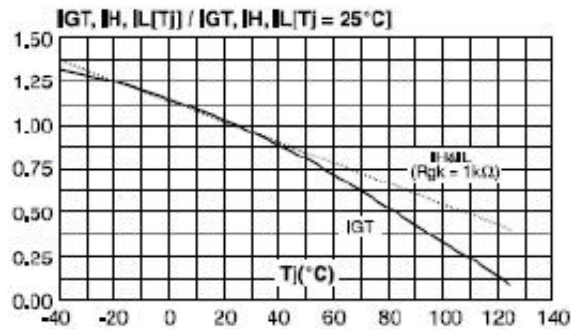
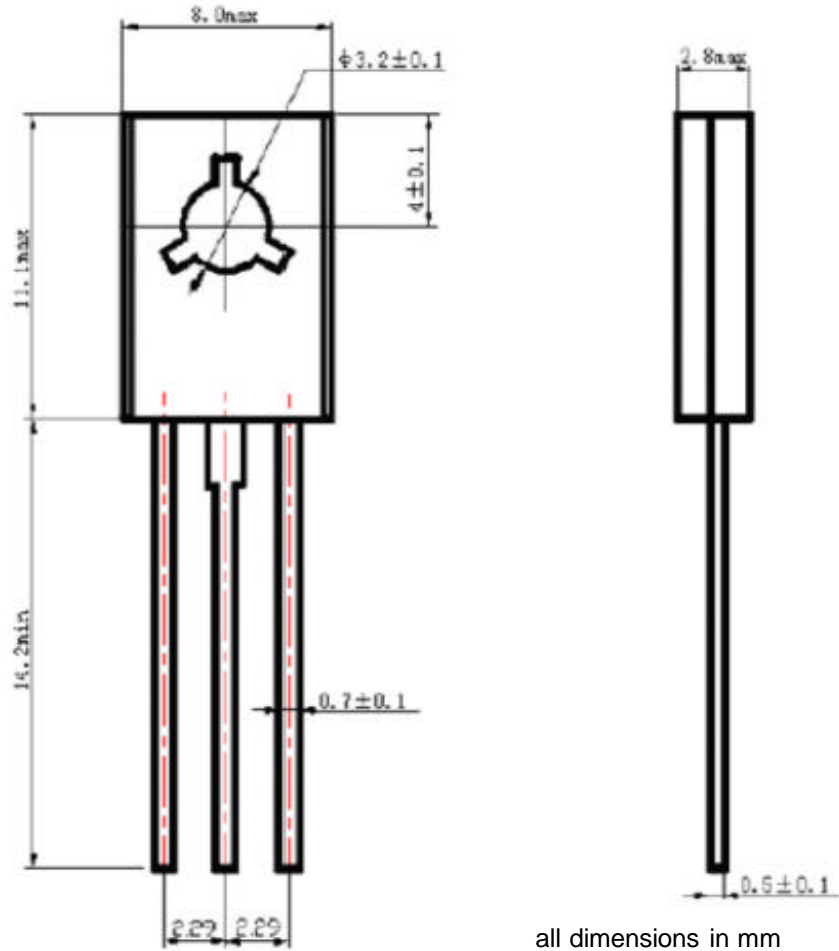


FIG. 3 Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).



### TO-126 PACKAGE OUTLINE AND DIMENSION





Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



## Customer Notes

### Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

### Disclaimer

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